

isc Silicon NPN Power Transistor

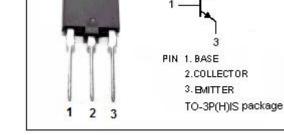
BU2523AX

DESCRIPTION

- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)}= 800V (Min)
- · High Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

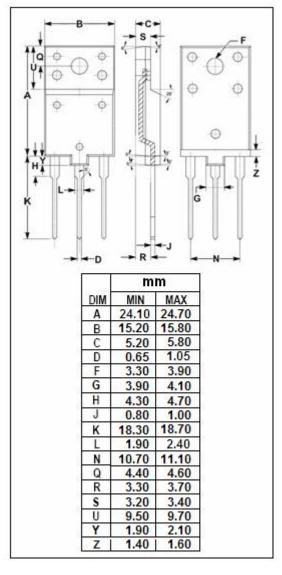
 Designed for use in horizontal deflection circuits of HDTV receivers and pc monitors.



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|--|---------------------|------------|--|
| V _{CES} | Collector- Emitter Voltage(V _{BE} = 0) | 1500 | V | |
| V _{CEO} | Collector-Emitter Voltage | 800 | V | |
| V _{EBO} | Emitter-Base Voltage | 7.5 | V | |
| Ic | Collector Current- Continuous | 11 | А | |
| I _{CM} | Collector Current-Peak | 29 | Α | |
| I _B | Base Current- Continuous | 7 | Α | |
| I _{BM} | Base Current-Peak | 10 | Α | |
| Pc | Collector Power Dissipation @ T _C =25 °C 45 | | W | |
| TJ | Junction Temperature | ion Temperature 150 | | |
| T _{stg} | Storage Temperature Range | -55~150 | $^{\circ}$ | |

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|-------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance,Junction to Case | 2.8 | °C/W |





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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|-----------------------|--------------------------------------|--|-----|------|------------|------|
| V _{CEO(SUS)} | Collector-Emitter Sustaining Voltage | I _C =50mA ; I _B = 0 | 800 | | | V |
| V _{(BR)EBO} | Emitter-Base Breakdown Voltage | I _E = 1mA; I _C = 0 | 7.5 | | | V |
| V _{CE} (sat) | Collector-Emitter Saturation Voltage | I _C = 5.5A; I _B = 1.1A | | | 5.0 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 5.5A; I _B = 1.1A | | | 1.0 | V |
| I _{CES} | Collector Cutoff Current | V _{CE} = 1500V ; V _{BE} = 0 V _{CE} = 1500V ; V _{BE} = 0; T _C =125℃ | | | 1.0 2.0 | mA |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 7.5V ; I _C = 0 | | | 1.0 | mA |
| h _{FE-1} | DC Current Gain | I _C = 1A; V _{CE} = 5V | | 14 | | |
| h _{FE-2} | DC Current Gain | Ic= 5.5A; Vc== 5V | 5 | | 10.3 | |

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